September 2015

KSA539
PNP Epitaxial Silicon Transistor

Features

- Low Frequency Amplifier
- Complement to KSC815
- Collector-Base Voltage: V_{CBO} = -60 V
- Collector Power Dissipation : P_C = 400 mW
- Suffix “-C” means Center Collector (1. Emitter 2. Collector 3. Base)
- Non Suffix “-C” means Side Collector (1. Emitter 2. Base 3. Collector)

Straight Lead
Bulk Packing

Bent Lead
Tape & Reel
Ammo Packing

TO-92
1. Emitter
2. Base
3. Collector

Ordering Information

Part Number	Top Mark	Package	Packing Method
KSA539CYTA	A539	TO-92 3L	Ammo

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-60	V
V_{CEO}	Collector-Emitter Voltage	-45	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-200	mA
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 to 150	°C

Thermal Characteristics[1]

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
P_C	Collector Power Dissipation	400	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	310	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{CBO}	Collector-Base Breakdown Voltage	I_C = -100 μA, I_E = 0	-65			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = -10 mA, I_B = 0	-45			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E = -10 μA, I_C = 0	-5			V
I_{CBO}	Collector Cut-Off Current	V_{CB} = -45 V, I_E = 0			-100	nA
I_{EBO}	Emitter Cut-Off Current	V_{EB} = -3 V, I_C = 0			-100	nA
h_{FE}	DC Current Gain	V_{CE} = -1 V, I_C = -50 mA	40		240	
V_{BE}(on)	Base-Emitter On Voltage	V_{CE} = -1 V, I_C = -10 mA	-0.60	-0.65	-0.90	V
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = -150 mA, I_B = -15 mA		-0.25	-0.50	V
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = -150 mA, I_B = -15 mA		-0.9	-1.2	V

h_{FE} Classification

Classification	R	O	Y
h_{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Performance Characteristics

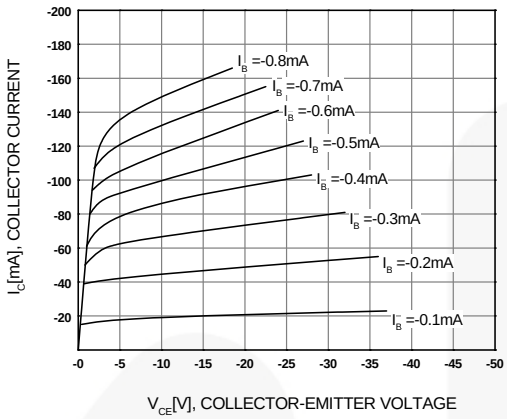

Figure 1. Static Characteristic

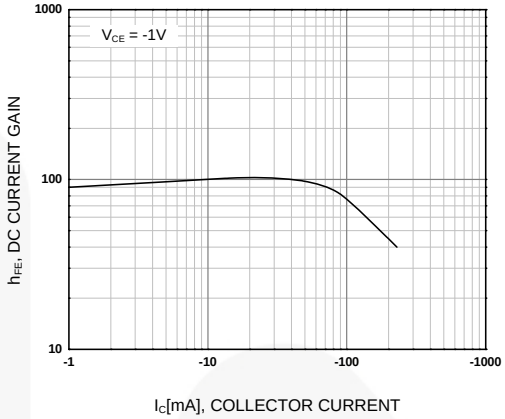

Figure 2. DC Current Gain

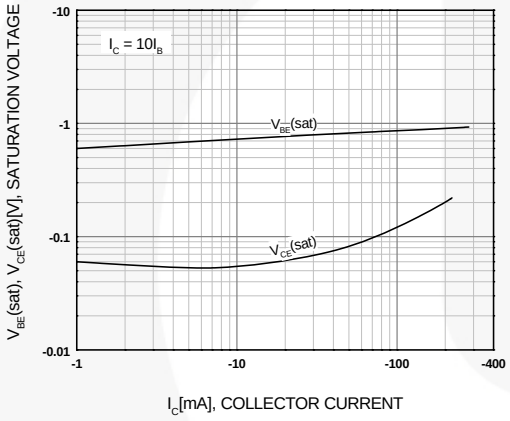

Figure 3. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

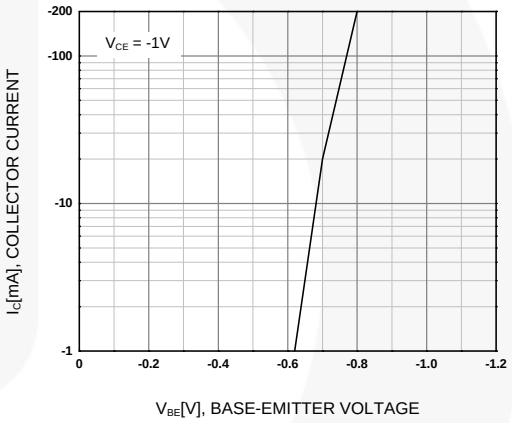

Figure 4. Base-Emitter On Voltage

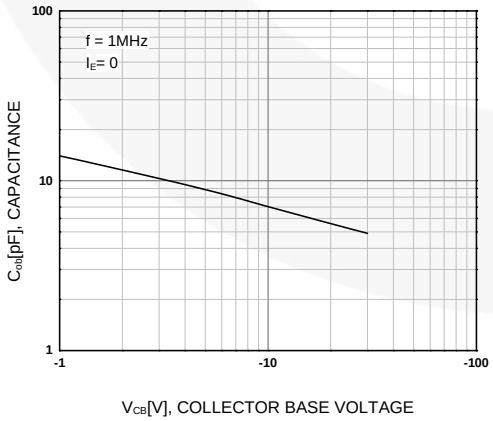

Figure 5. Collector Output Capacitance

Physical Dimensions

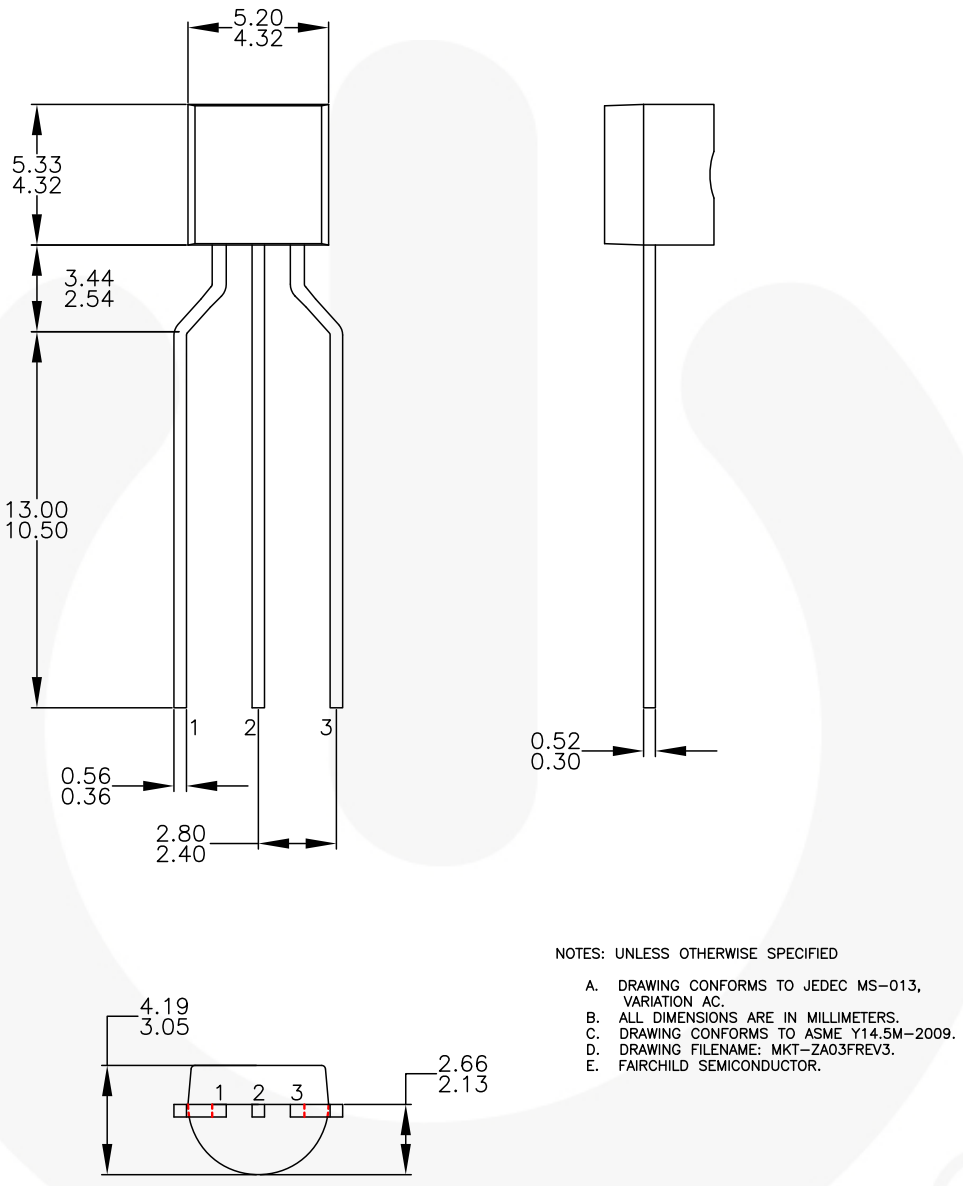

Figure 6. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form, Ammo Type

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